



Development of a high-power coherent THz sources and THz-TDS system on the basis of a compact electron linac

Masafumi Kumaki A)

Ryunosuke Kuroda^{B)}, Hiroyuki Toyokawa^{B)}, Yoshitaka Taira^{B)}, Kawakatsu Yamada^{B)}, Kazuyuki Sakaue^{A)}, Masakazu Washio^{A)}

^{A)} Advanced Research Institute for Science and Engineering (RISE), Waseda University, Japan
^{B)} National Institute of Advanced Industrial Science and Technology (AIST), Tsukuba, Japan



<u>Outline</u>

- 1. Introduction
 - What's THz?
 - Motivation of our work
- 2. THz Generation and Application with the Accelerator
 - THz Coherent Radiation
 - THz Imaging and THz-TDS system
- 3. Experiment
 - S-band Linac at AIST
 - Characteristics of Coherent Transition Radiation
 - Results of THz-TDS System
- 4. Summary



THz Wave

Terahertz wave (THz wave) is electromagnetic wave located between radio frequency and infrared light.



National Institute of Advanced Industrial Science and Technology (AIST) & Waseda Univ. Washio Lab.



3





Motivation

Identification of illegal drugs and explosives hidden in envelopes for security field using THz radiation.

Why THz?

- Explosives and drugs have a characteristic THz spectrum
- THz wave transmits through papers, envelopes and plastics

Our Research

- High power THz source
- Development of spectroscopy system





<u>Outline</u>

1. Introduction

- What's THz?
- Motivation of our work
- 2. THz Generation and Application with the Accelerator
 - THz Coherent Radiation
 - THz Imaging and THz-TDS system
- 3. Experiment
 - S-band Linac at AIST
 - Characteristics of Coherent Transition Radiation
 - Results of THz-TDS System

4. Summary





THz Coherent Radiation

High Power THz Coherent Radiation

 \implies The electron bunch is compressed to less than 1ps with magnetic bunch compressor.

Incoherent Radiation (bunch length > wavelength) $I_{inc} \propto N$ Electron $N = 6 \times 10^9$ @ 1nC bunch P: Intensity of Synchrotron Radiation Number of electrons Ν· ~×10^{9~10} **Coherent Radiation** (bunch length < wavelength) Intensity $I_{\rm coh} \propto N^2$ $I_{coh} = (1 + (N - 1)f(\omega))I_{inc}(\omega)$ $f(\omega)$: Form factor $f(\omega) = e^{-\frac{(\omega\sigma_z)^2}{2}}$





Our methods for THz generation



Characteristics of CSR and CTR

Generation Method	①Coherent Synchrotron Radiation (CSR)	②Coherent Transition Radiation (CTR)
Peak Power	High	High
Source size	Large	Small
Divergence	Large	Small
Polarization	Horizontal	Radial
	THz Imaging	THz-Time Domain Spectroscopy (THz-TDS)





THz Scanning Imaging with CSR







Why do we need the THz TDS System ? -for identifying materials-









<u>Outline</u>

1. Introduction

- What's THz?
- Motivation of our work
- 2. THz Generation and Application with the Accelerator
 - THz Coherent Radiation
 - THz Imaging and THz-TDS system
- 3. Experiment
 - S-band Linac at AIST
 - Characteristics of Coherent Transition Radiation
 - Results of THz-TDS System

4. Summary



for Imaging



S-band Linac at AIST

			THz-CSR	I
Energy	40MeV		port×2	
Charge per bunch	1nC		90° Bending	dump
Bunch length	<1ps (estimated 500fs)		Al Plate	
Rep. rate	1 - 50Hz	THz	Application	for TDS
Klystron 20MW UV laser Photocathode RF-Gun Accelera	Accelerate Section	Magnetic Compres 45° Be mag	sor ending gnet Q-mag	gnet







THz-CTR (Coherent Transition Radiation)





THz-CTR Electric Field Profile and Polarization







20

15

Polarization control of CTR









When the THz-CTR and probe laser pass through the EO crystal at the same time, the refractive index of the crystal is changed by the THz electric fields.

 \Rightarrow The polarization of the probe laser is also changed.

We measure the intensity difference between the p- and s-polarization of the probe laser.

- \Rightarrow The difference corresponds to the intensity of THz electric field.
 - The temporal waveform is obtained with the pump-probe technique and the THz spectrum is calculated by Fourier transform.













The THz temporal waveform has been successfully obtained.

The measured THz pulse length has been estimated to be about 1.6 ps (rms). It is larger than the expected value (= electron bunch length, 0.5 ps) due to the time jitter between the probe laser and THz pulse and the finite frequency response of EO crystal depending on its thickness.





THz-TDS Result



FFT



<u>Summary</u>

- THz radiation has been generated using coherent transition radiation (CTR) with polarization control for THz time domain spectroscopy (THz-TDS) at AIST.
- The THz-CTR-TDS system has been constructed with EO sampling method. The THz temporal waveform has been successfully measured with this system.
- In the next step, we will reduce the jitter and optimize the thickness of the EO crystal in order to improve the measurement accuracy of this system and to extend the measured spectral range. In near future, we will apply the THz CTR-TDS system to investigation of explosives and illegal drugs.





Thank you for your attention

National Institute of Advanced Industrial Science and Technology (AIST) & Waseda Univ. Washio Lab.

20 21







1shot THz-TDS using chirped probe laser





Timing synchronization system (Low-jitter)

- Probe laser is synchronized to the their mode-lock frequencies (79.3MHz : fundamental).
- Relative timing jitter between the master and the laser is
 - about 1ps (synchronized with fundamental freq. : in this experiment)
- I < 10fs. (synchronized with 36th harmonics freq. :the acceleration frequency (2856MHz))

(F. Sakai, Proceedings of SPIE, 5194, 149-156 (2003)

Measured using time domain demodulation technique with the vector signal analyzer by measuring the amplitude monitor and phase noise.



This synchronization system has been accomplished for the 150 fs laser Compton X-ray generation. It is easily to apply to the THz-TDS.











THz Power-meter(0.1~2THz)

VDI - Erickson Power Meters

AIST

The VDI Erickson Power Meter is a calibrated calorimeter-style power meter for 75 GHz to > 2000 GHz applications. The sensor head has a WR10 input and VDI sells a variety of input waveguide tapers for use at high frequencies (see application note). Contact VDI for additional information.



- Analog output BNC connector on back panel: 0-10V corresponds to 0-full scale meter reading.
- RS232 data output port.
- ▶ Calibration factor adjustment of up to ±29.9 dB using digi switches
- Temperature drift is compensated to <2 µW/°C.

The sensor has a thermal time constant (1/e) of 6 seconds. For faster response, the load is heated to a nearly constant temperature using a feedback loop. When input power is applied, the heater power is reduced, and the circuit measures the change, which is equivalent to the input power. The loop gain varies with the power to be measured, changing the response time. For highest sensitivity, no feedback is used on the lowest scale.

Typical performance

Scale (FS)	<u>time for 90%</u> response*	RMS noise
200 mW	0.1 s	~3 µW
20 mW	0.15 s	~0.3 µW
2 mW	1.3 s	0.1 µW
200 µW	15 s	0.01 µW

O1-2 nJ/pulse/1mm × 2mm

⇒ Peak Power about 1 kW/mm² @1.4m point from Source point (THz Beam size at this point : about 20cm)







Theory of EO sampling method using ZnTe crystal

Phase retardation of probe laser ∝ Intensity of THz electric field

Probe transmission of the polarizer $T=(1 + sin\Gamma/2)$ (Γ is magnitude of induced phase retardation)

$$\Gamma = \frac{2\pi L}{\lambda} n^3 \gamma_{41} E_{THz} = \frac{\pi E_{THz} L}{V_{\lambda/2}}$$

- λ : probe wavelength,
- L : crystal length
- *n* : probe refractive index
- γ_{41} : EO coefficient involved in the Pockels effect
- E_{THz} : THz electric field
- $V_{\lambda/2}$: half-wave voltage of about 3 kV@800nm

Phase retardation is increased with the crystal length *L*. But the length is limited by the phase matching and a coherence length between the THz pulse and the probe pulse.

 \Rightarrow We should determine the crystal length.



Electro optical (EO) crystal





where φ is the angle between the major ellipse axis y" and the y' axis. When the phase retardation is largest with $\Phi=90^{\circ}$, the angle φ is equal to $\varphi=45^{\circ}$, which means that one should set the polarization of the probe beam to be parallel to either y' [±1,-+1,0] or z' [0,0, ±1] for optimized EO sampling geometry.

phase retardation



$$\Gamma = \frac{\Delta I}{I_0} = \frac{2\pi d}{\lambda} n_0^3 r_{41} E_{THz}$$

Q. Chen, M. Tani,* Zhiping Jiang, and X.-C. Zhang. Electro-optic transceivers for terahertz-wave applications Vol. 18, No. 6/June 2001/J. Opt. Soc. Am. B page823

National Institute of Advanced Industrial Science and Technology (AIST) & Waseda Univ. Washio Lab.

28 / 20





Frequency Response dependence against the thickness of EO crystal



c : speed of light n_{THz} : THz refractive index n_{eff} : effective refractive index of probe pulse

THz refractive index:

THz: ~ 2THz

$$n_{THz} = \sqrt{(289.27 - 6f^2)/(29.16 - f^2)}$$



Coherence length of ZnTe crystal as a function of THz frequency

ZnTe crystal length < 2.7 mm



Bunch Compression

The head and tail of the bunch correspond to high-energy and low-energy parts, respectively.





After this section longitudinal $z_f = z_0 + R_{56} \left(\frac{\Delta E}{E} \right)$

 $E < E_0$

The high-energy and low-energy electrons pass along the long path and the short path respectively after optimising magnetic fields of Q-magnets for the bunch compression.



z

E >





RMS Bunch Length Monitor







Theoretical THz CSR generation

Synchrotron radiation less than critical frequency ωc is coherently emitted from a ultra short electron bunch (σ_z). Its frequency is expressed by

$$\omega_c = \pi c / \sigma_z$$

The total photons (I_{tot}) with both of incoherent and coherent radiation are derived from equations

$$I_{tot} = I_{inc} (1 + (N - 1)f(\omega))$$
$$f(\omega) = e^{\frac{(\omega \sigma_z)^2}{2}}$$

 I_{inc} : photos of incoherent radiation N: number of electrons in the bunch $f(\omega)$: fourier transform of the longitudinal electron density with Gaussian bunches(σ_z)



Enhancement factor of CSR as a function of frequency by changing electron rms bunch length (500 fs, 300 fs, 100 fs, Incoherent radiation)

20





THz Detector (Schottky Diode)

Responsivity (V/W)

0 + 220

230

240

250





Scanning electron micrograph of a planar Schottky barrier diode. Chip dimensions approximately 180x80x40 µm

270

Frequency (GHz)

260

280

290

300

310

320

330

WR3.4ZBD 1-13 Responsivity

Tunerless Design No bias required No mechanical tuners NEP: 1E-11 W/√Hz (typ.) Responsivity: 1500 V/W (typ.) Input: WR-3.4 (UG-387/UM) Output: 2.9mm Coax Shown with optional horn antenna





Bunch Compression Simulation with TRACE3D

🔗 TRACE 3D --- INTERACTIVE BEAM TRANSPORT PROGRAM 03/23/2012 VERSION 69ly file 遷移放射.t3d _ 0 X File Hard Copy Driver Options Commands Help BEAM AT NEL1= 1 BEAM AT NEL2= 26 т= 2856.0mA W= 39.0000 H A= -3.0500 B= 132.80 B= 130.20 39.0000 MeV B= 2.53507E-03 H A=-0.11093 FREQ=2856.00MHz WL= 104.97mm V A= -3.0300 V A=-3.09407E B= 9.28636E-03 EMITI= 0.900 1.000 1820.00 EMITO= 3.669 1.000 1890.83 N1= N2= 26 PRINTOUT VALUES VALUE PP PE 300.00000 9 -2.0451210 11 12 13 100.00000 3.93330 100.00000 14 100.00000 MATCHING TYPE = 11 DESIRED MODIFIED BEAM MATRIX S11 = 0.000000s33 = 0.000000 15.000 mm 0.500 mrad 0.300 mm 50.000 mrad х х šŏŏ = ŏ.ŏŏŏŏŏō s00 = 0.000000 MATCH VARIABLES (NC=4) Z A= 20.501 B= 4,49000E-02 Z A= 4.82096E-02 B= 1.10423E-04 MPP MPE VALUE \$ 21 23 25 2.83744 7 -5.028471 \geq 6.68250 \geq 2 CODE: Trace 3-D v691y FILE: 'J^Ú•úŽË.t3d DATE: 03/23/2012 TIME: 14:36:15 5000.00 keV 10.000 Deg х 10.000 Deg х 5000.00 keV VP1= NP2= 31 30.0 Deg /(Long.) 70.00 mm (Horiz) 5 6 1 23 7 8 Q 18 19 20 24 25 26 27 28 29 30 31 σ_{min} =500fs Spotsize_{min}=100um 70.00 mm (Vert) Length= 5626.64mm





Second order, Third order effect

A path length difference for particles with a relative energy deviation δ is given by:

$$\Delta z = \eta \delta = R_{56} \delta + T_{566} \delta^2 + U_{5666} \delta^3 \dots$$

- η : longitudinal dispersion
- δ : relative energy deviation (= ΔE/E)
- R₅₆ : linear longitudinal dispersion (leading term for bunch compression)
- T₅₆₆ : second order longitudinal dispersion
- U₅₆₆₆ : third order longitudinal dispersion





Possibility of Donuts profile

1Radial Polarization

2 Azimuth Polarization





M.Endo, Radial Polarization http://teamcoil.sp.u-tokai.ac.jp/kenkyu/Resonator/Radial/

FEASIBILITY TEST OF LASER-INDUCED SCHOTTKY-EFFECT-GATED PHOTOCATHODE RF GUN Proc. of FEL 2007 (2007) pp.382-385

Radial Polarizer





CTR with radial polarizer has also the donuts profile









THz Spectral Splitters



Туре	NIR-THz spectral splitter	MIR-THz spectral splitter
Material of substrate	- HRFZ-Si - THz-grade crystal quartz	
Dimensions tolerance, mm	+/-0.25	
Clear aperture, %	90	
Surface quality, scr/dig	60/40	
Surface accuracy, mm	+/-0.01 deviation from ideal plane	
Coating	High-reflection dielectric coating (R>90%) @ 730- 860 nm	High-reflection dielectric coating (R>90%) @ 9-11µm
Angle of incidence, arc. grad:	45	

The following THz spectral splitters are available from stock:

No.	Diameter		Thickness
	mm	inches	mm
1	25.4	1.0	1.0







Fig.2 Transmission of NIR-THz spectral splitter (two types of substrate).



0.12

0.1

0.08

0.06

0.04

0. 02

0

-5

0

5

10

15

Time [ps]

20

25

Intensity [V]



No sample



Time [ps]



PTFE





National Institute of Advanced Industrial Science and Technology (AIST) & Waseda Univ. Washio Lab.

30

35







CSR electric field profile





The size of THz-CSR is about 20 cm at the THz window. (> the size of beam pipe)





